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# HiPerFRED™ Epitaxial Diode

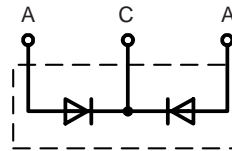
## with common cathode and soft recovery

$$I_{FAV} = 2 \times 15 \text{ A}$$

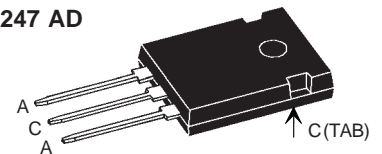
$$V_{RRM} = 400 \text{ V}$$

$$t_{rr} = 30 \text{ ns}$$

$V_{RSM}$	$V_{RRM}$	Type
V	V	
400	400	DSEC 30-04A



TO-247 AD



A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$	$T_C = 145^\circ\text{C}$ ; rectangular, $d = 0.5$	50	A
$I_{FAVM}$		15	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine	tbd	A
$E_{AS}$	$T_{VJ} = 25^\circ\text{C}$ ; non-repetitive $I_{AS} = \text{tbd A}$ ; $L = \text{tbd } \mu\text{H}$	tbd	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_R \text{ typ.}$ ; $f = 10 \text{ kHz}$ ; repetitive	tbd	A
$T_{VJ}$		-55...+175	$^\circ\text{C}$
$T_{VJM}$		175	$^\circ\text{C}$
$T_{stg}$		-55...+150	$^\circ\text{C}$
$P_{tot}$	$T_C = 25^\circ\text{C}$	95	W
$M_d$	mounting torque	0.8...1.2	Nm
Weight	typical	6	g

### Features

- International standard package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

### Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{RM}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

Dimensions see Outlines.pdf

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$ ①	$V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ ; $T_{VJ} = 150^\circ\text{C}$	100	$\mu\text{A}$
		0.5	mA
$V_F$ ②	$I_F = 15 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$	1.06	V
		1.47	V
$R_{thJC}$		1.6	K/W
$R_{thCH}$		0.25	K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 100 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	30	ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 25 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ ; $T_{VJ} = 100^\circ\text{C}$	5.0	6.3 A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle &lt; 2.0 %

 ② Pulse Width = 300  $\mu\text{s}$ , Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

**Recommended replacement:  
DPG 30C400HB**